Product data sheet

1. General description

Silicon Carbide Schottky diode in a DFN 8*8 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- · Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- · Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				650		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; $T_c \le$ 144 °C; Fig. 1; Fig. 2; Fig. 3		8		А	
T_j	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 8 \text{ A}; dI_F/dt = 500 \text{ A/}\mu\text{s}; V_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 7$		-	12	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	[]	K — A
2	n.c.	not connected	5	001aaa020
3	А	anode		
4	А	anode	0	
5	К	mounting base; connected to cathode	1 2 3 4	

6. Ordering information

Table 3. Ordering information

Type number	Package	Orderable part number	Packing	Small packing	Package	Package
	name		method	quantity	version	issue date
WNSC5D08650T	DFN8*8	WNSC5D08650T6J	Tape	3000	DFN8X8N	25-Dec-2019

7. Marking

Table 4. Marking codes

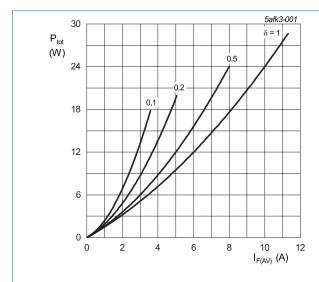
Type number	Marking codes
WNSC5D08650T	WNSC5D 08650T

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; T _c ≤ 144 °C; Fig. 1; Fig. 2; Fig. 3		8	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _c ≤ 144 °C; square-wave pulse		16	Α
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		48	А
	forward current	$t_p = 10 \mu s; T_{j(init)} = 25 °C; square-wave pulse$		520	Α
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$		11.52	A ² s
T _{stg}	storage temperature			-55 to 175	°C
T _j	junction temperature			-55 to 175	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.395 \text{ V}; \text{ R}_s = 0.1006 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

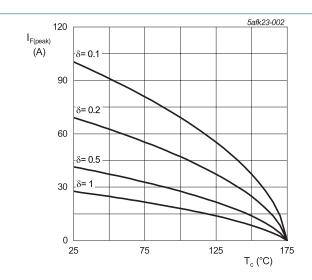
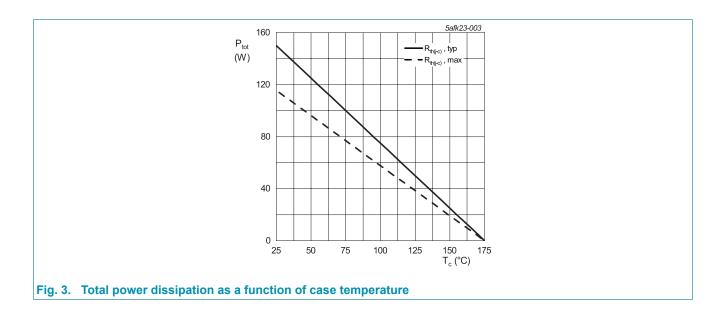


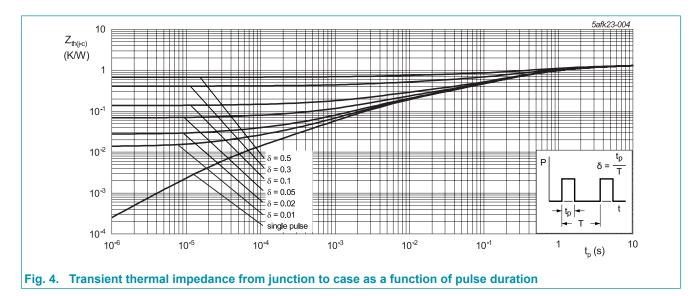
Fig. 2. Current derating as a function of case temperature



9. Thermal characteristics

Table 6. Thermal characteristics

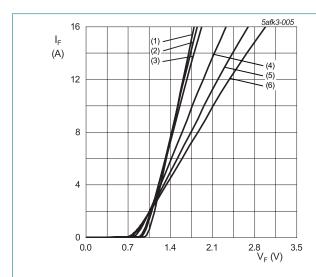
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-c)}	thermal resistance from junction to case	Fig. 4		-	1	1.3	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	50	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
V_{F}	forward current	I _F = 8 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.45	1.70	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.80	2.20	V
		I _F = 8 A; T _j = 175 °C; <u>Fig. 5</u>		-	2.00	2.30	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>		-	0.4	40	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>		-	20	200	μA
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	12	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	267	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C		-	32	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C		-	31	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 4.2 \text{ A}; L = 5 \text{ mH}; T_{j(init)} = 25 \text{ °C}$		45	-	-	mJ



 V_o = 1.395 V; R_s = 0.1006 Ω

(1) $T_j = -55$ °C; typical values (2) $T_j = 0$ °C; typical values

(3) T_i = 25 °C; typical values

(4) T_i = 100 °C; typical values

(5) T_i = 150 °C; typical values

(6) T_i = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

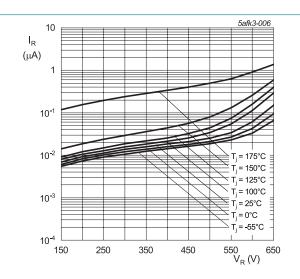
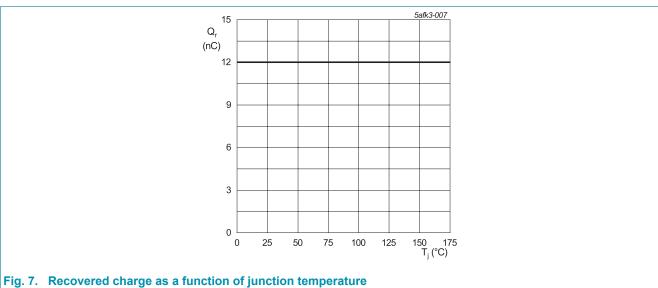
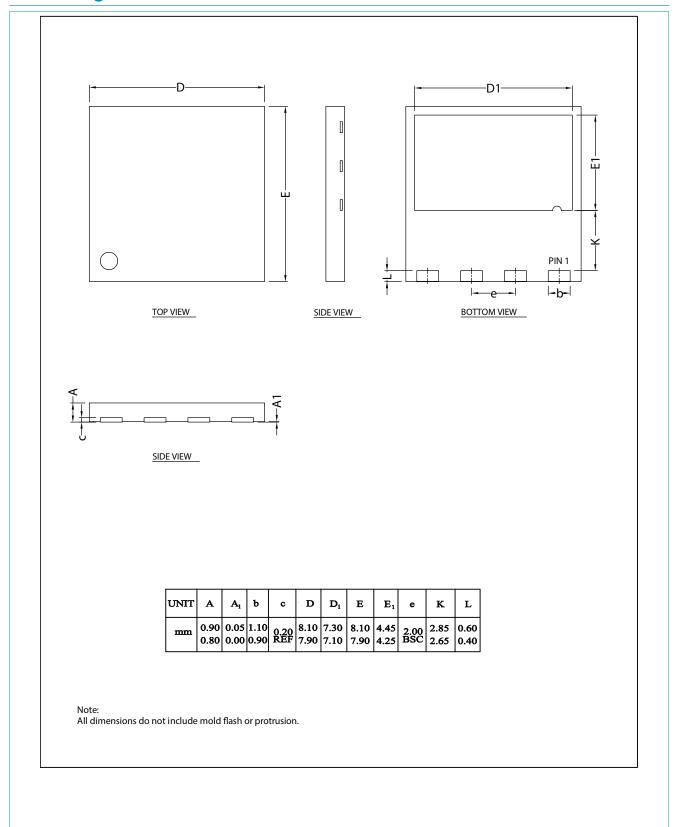


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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